

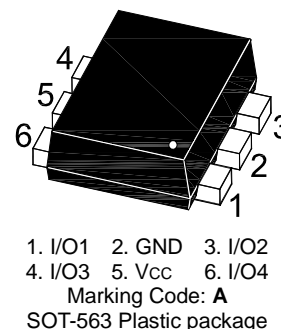
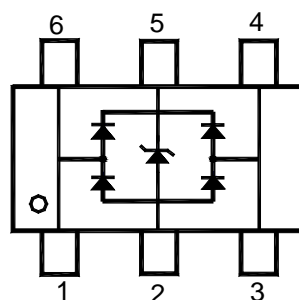
E5V0VUDE2H

Transient Voltage Suppressors Array

ESD protection

Features

- Protects up to two I/O lines & power line
- Low leakage current and clamping voltage
- Low Capacitance

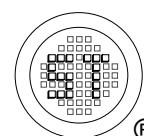


Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p = 8/20 \mu\text{s}$)	P_{PK}	80	W
Peak Pulse Current ($t_p = 8/20 \mu\text{s}$)	I_{PP}	5	A
IEC61000-4-2 (ESD) Air Contact	V_{ESD}	30 30	KV
Operating Temperature Range	T_j	-55 to + 125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Reverse Stand-Off Voltage Between I/O lines to Gnd or I/O to I/O	V_{RWM}	-	5	V
Reverse Breakdown Voltage at $I_R = 1 \text{ mA}$, Between I/O lines to Gnd	$V_{(BR)R}$	6	9	V
Reverse Current at $V_{RWM} = 5 \text{ V}$, Between I/O lines to Gnd or I/O to I/O	I_R	-	0.1	μA
Clamping Voltage at $I_{PP} = 1 \text{ A}$, $t_p = 8/20 \mu\text{s}$, Between I/O to Gnd at $I_{PP} = 5 \text{ A}$, $t_p = 8/20 \mu\text{s}$, Between I/O to Gnd	V_C	- -	11 16	V
Junction Capacitance at $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$, Between I/O to Gnd at $V_R = 0 \text{ V}$, $f = 1 \text{ MHz}$, Between I/O to I/O	C_j	- -	0.9 0.5	pF



Electrical Characteristics Curves

Fig 1. Pulse Waveform

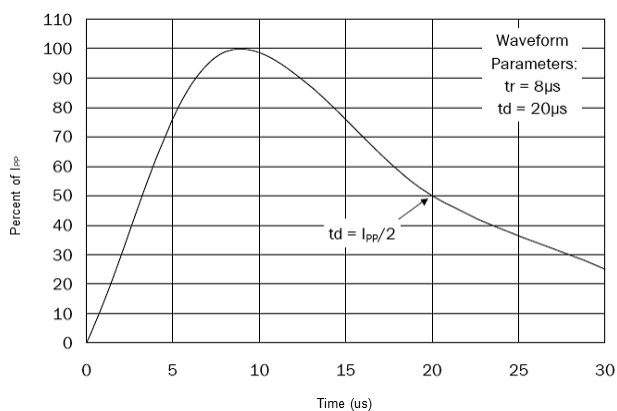


Fig 2. Power Derating Curve

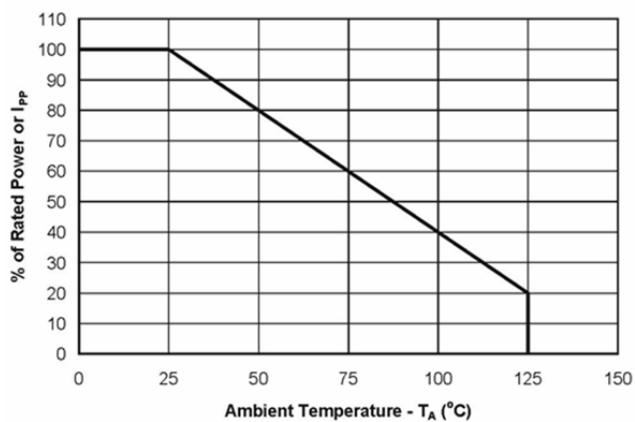


Fig 3. TLP

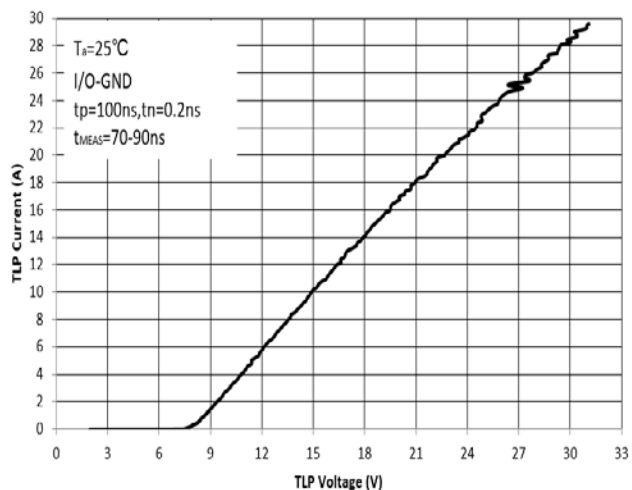


Fig 4. Clamping Voltage vs. Peak Pulse Current

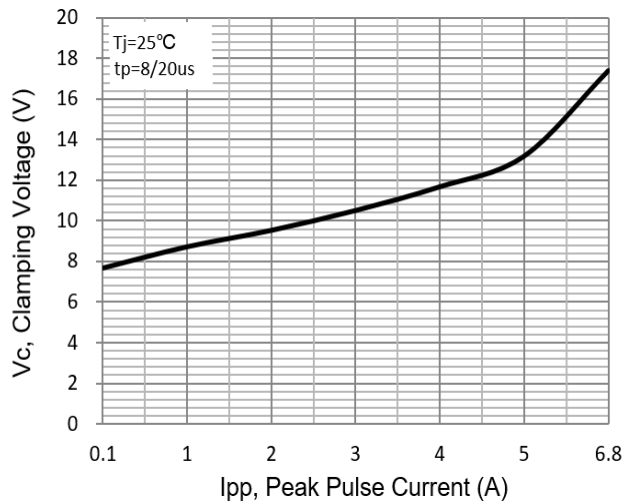
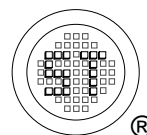
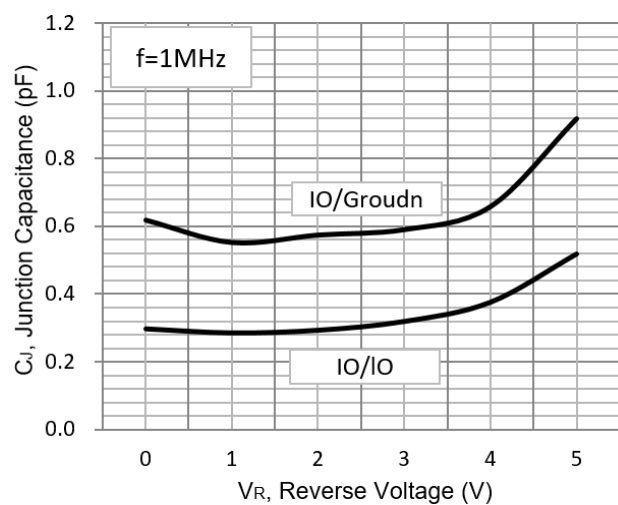


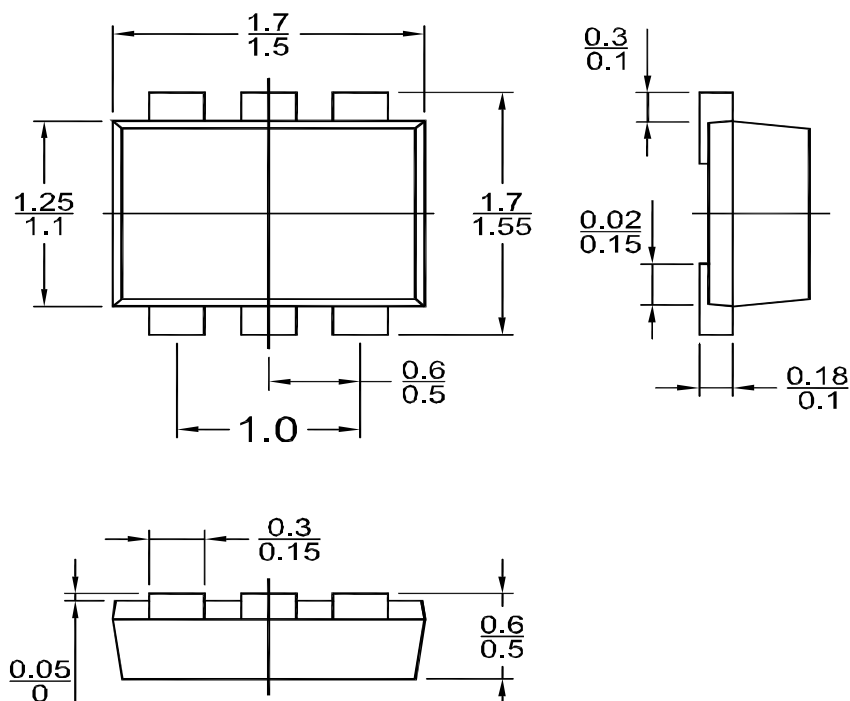
Fig 5. Junction Capacitance vs. Reverse Voltage



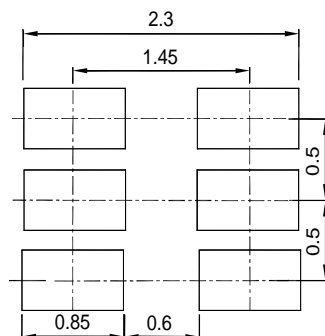
E5V0VUDE2H

Package Outline Dimensions (Units: mm)

SOT-563



Recommended Soldering Footprint



Packing information

Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-563	8	4 ± 0.1	0.157 ± 0.004	178	7	4,000

Marking information

" A " = Part No.
" YM " = Date Code Marking
" Y " = Year
" M " = Month
Font type: Arial

